

N-Channel Super Junction Power MOSFET $\, III \,$

General Description

The series of devices use advanced trench gate super junction technology and design to provide excellent R_{DS(ON)} with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

Features

- Optimized body diode reverse recovery performance
- ●Low on-resistance and low conduction losses
- Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ●ROHS compliant

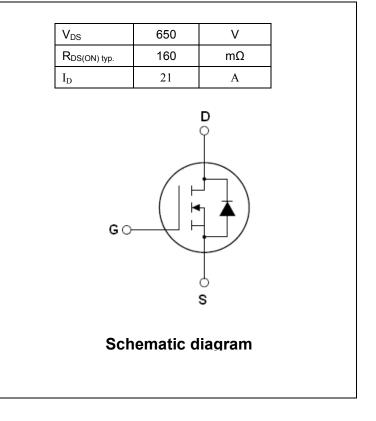
Application

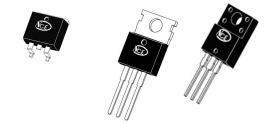
- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)
- LLC Half-bridge

Package Marking And Ordering Information

Device	Device Package	Marking
NCE65TF180	TO-220	NCE65TF180
NCE65TF180F	TO-220F	NCE65TF180F
NCE65TF180D	TO-263	NCE65TF180D

Table 1. Absolute Maximum Ratings (T_c=25℃)





TO-263

TO-220

TO-220F

Parameter	Symbol	NCE65TF180 NCE65TF180D	NCE65TF180F	Unit
Drain-Source Voltage (VGs=0V)	VDS	6	50	V
Gate-Source Voltage (VDS=0V), AC (f>1 Hz)	Vgs	±30		V
Continuous Drain Current at T _C =25°C	I _{D (DC)}	21	21*	А
Continuous Drain Current at T _C =100°C	I _{D (DC)}	13.2	13.2*	А
Pulsed drain current (Note 1)	I _{DM (pluse)}	84	84*	А
Maximum Power Dissipation(T _C =25 [°] C)	PD	188	33.8	W
Derate above 25°C		1.5	0.27	W/°C
Single pulse avalanche energy (Note 2)	Eas	441		mJ
Avalanche current ^(Note 1)	I _{AR}	10.5		Α
Repetitive Avalanche energy $\!$	E _{AR}	0.7		mJ



NCE65TF180D,NCE65TF180,NCE65TF180F

Parameter	Symbol	NCE65TF180 NCE65TF180D	NCE65TF180F	Unit
Drain Source voltage slope, $V_{DS} \leq 480 V$,	dv/dt	50		V/ns
Reverse diode dv/dt, $V_{DS} \leq 480 \text{ V}, I_{SD} < I_D$	dv/dt	5	0	V/ns
Operating Junction and Storage Temperature Range	T_J, T_{STG}	-55	+150	°C

* limited by maximum junction temperature

Table 2. Thermal Characteristic

Parameter		Symbol	NCE65TF180	NC		80E	Unit	
		Symbol	NCE65TF180D		NCE65TF180F		Unit	
Thermal Resistance, Junction-to-Case (Maximum)		R _{thJC}	0.66		3.69		°C /W	
Thermal Resistance, Junction-to-Ambient (Ma	aximum)	R _{thJA}	62.5		80		°C /W	
Table 3. Electrical Characteristics (TA=25 °C unless otherwise noted)								
Parameter	Symbo	ol Co	ndition	Min	Тур	Max	Unit	
On/off states								
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0	V Ι _D =250μΑ	650			V	
Zero Gate Voltage Drain Current(Tc=25°C)	I _{DSS}	V _{DS} =6	50V,V _{GS} =0V			2	μA	
Zero Gate Voltage Drain Current(Tc=125°C)	I _{DSS}	V _{DS} =6	50V,V _{GS} =0V			100	μA	
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±	20V,V _{DS} =0V			±100	nA	
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V	_{GS} ,I _D =250µA	3	3.5	4	V	
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10	0V, I _D =10.5A		160	199	mΩ	
Dynamic Characteristics								
Input Capacitance	Clss	V _{DS} =5	V _{DS} =50V,V _{GS} =0V,		2250		PF	
Output Capacitance	Coss	F=	1.0MHz		83		PF	
Effective output capacitance, energy related	C _{o(er)}	V _{GS} =0 V	V _{GS} =0 V,V _{DS} =0480 V		48		pF	
Effective output conscitutes time related	6	ID=cons	ID=constant, V _{GS} =0 V V _{DS} =0480V		200		~	
Effective output capacitance, time related	C _{o(tr)}	V _{DS}			200		pF	
Total Gate Charge	Q_g	V -4	- V _{DS} =480V,I _D =21A,		36		nC	
Gate-Source Charge	Q_gs		- V _{DS} =480V,I _D =21A, - V _{GS} =10V		14		nC	
Gate-Drain Charge	Q_gd	V	V _{GS} -IUV		8.5		nC	
Switching times								
Turn-on Delay Time	t _{d(on)}				11		nS	
Turn-on Rise Time	t _r	V _{DD} =3	80V,I _D =11A,		6		nS	
Turn-Off Delay Time	$t_{d(off)}$	R _G =4	Ω,V _{GS} =10V		61		nS	
Turn-Off Fall Time	t _f		1		4.5		nS	
Source- Drain Diode Characteristics								
Source-drain current(Body Diode)	I _{SD}	-	T - 05°0			21	А	
Pulsed Source-drain current(Body Diode)	I _{SDM}		– T _C =25°C			84	А	
Forward on voltage	V_{SD}	Tj=25°C,Is	Tj=25°C,ISD=21A,VGS=0V		0.9	1.3	V	
Reverse Recovery Time	t _{rr}		Tj=25°C,I⊧=11A,di/dt=100A/µs		160		nS	
Reverse Recovery Charge	Qrr	Tj=25°C,I _F =1			1.4		uC	
Peak Reverse Recovery Current	I _{rrm}				17		Α	

 $Notes \ 1. \\ \text{Repetitive Rating: Pulse width limited by maximum junction temperature}$

 $\textbf{2. } \textbf{T}_{j} \texttt{=} \texttt{25}^{\circ} \textbf{C}, \textbf{V}_{\text{DD}} \texttt{=} \texttt{50} \textbf{V}, \textbf{V}_{\text{G}} \texttt{=} \texttt{10} \textbf{V}, \textbf{R}_{\text{G}} \texttt{=} \texttt{25} \boldsymbol{\Omega}$



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

Figure1. Safe operating area for TO-220/TO-263

Figure2. Safe operating area for TO-220F

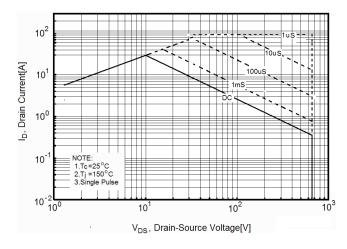


Figure3. Source-Drain Diode Forward Voltage

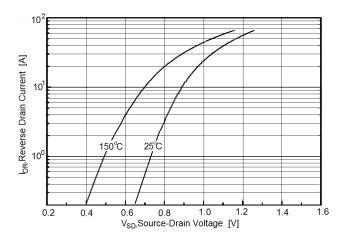
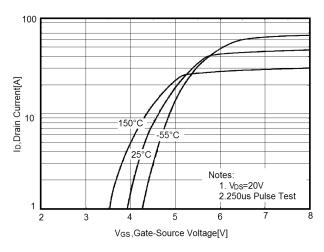


Figure5. Transfer characteristics



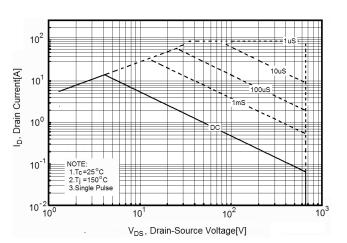


Figure4. Output characteristics

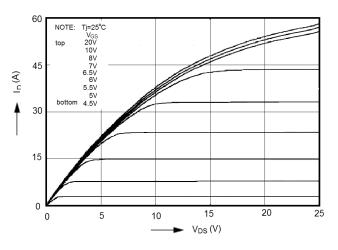
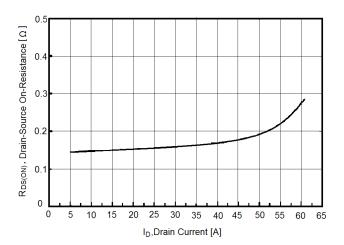


Figure6. Static drain-source on resistance





NCE65TF180D,NCE65TF180,NCE65TF180F

Figure7. R_{DS(ON)} vs Junction Temperature

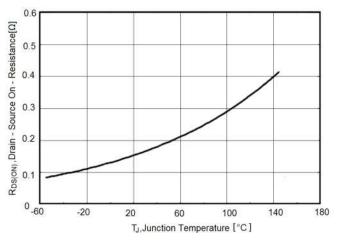


Figure8. BV_{DSS} vs Junction Temperature

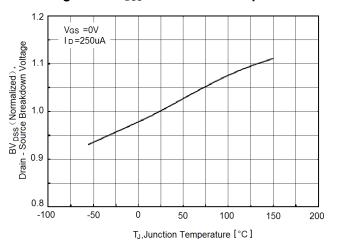


Figure9. Maximum I_D vs Junction Temperature

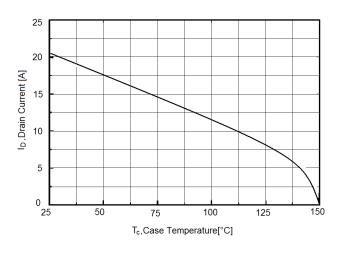


Figure10. Transient Thermal Impedance for TO-220

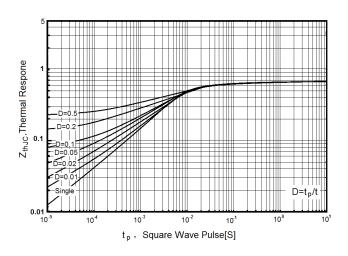


Figure11. Transient Thermal Impedance for TO-220F

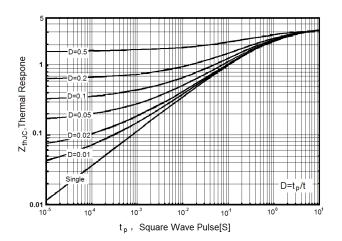


Figure12. Gate charge waveforms

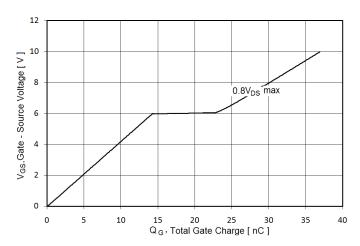
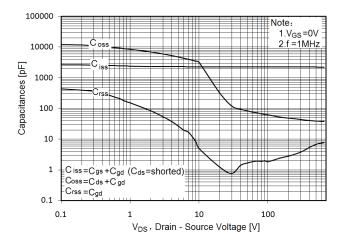




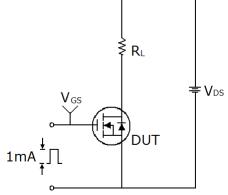
Figure13. Capacitance

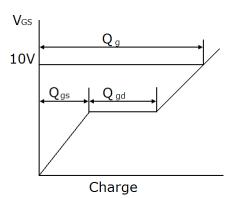




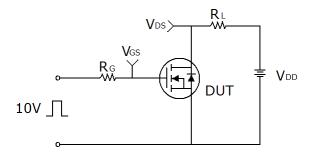
Test circuit

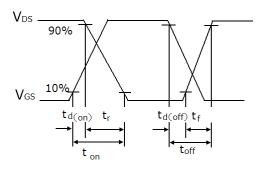
1) Gate charge test circuit & Waveform



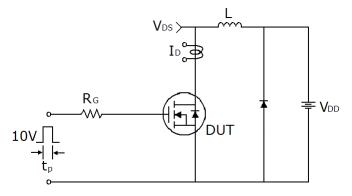


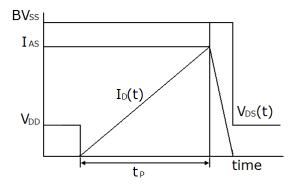
2) Switch Time Test Circuit:





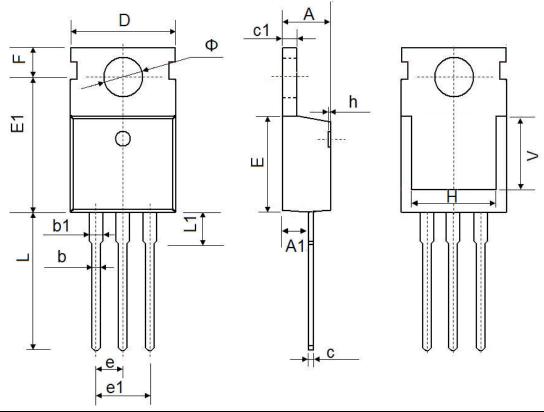
3) Unclamped Inductive Switching Test Circuit & Waveforms







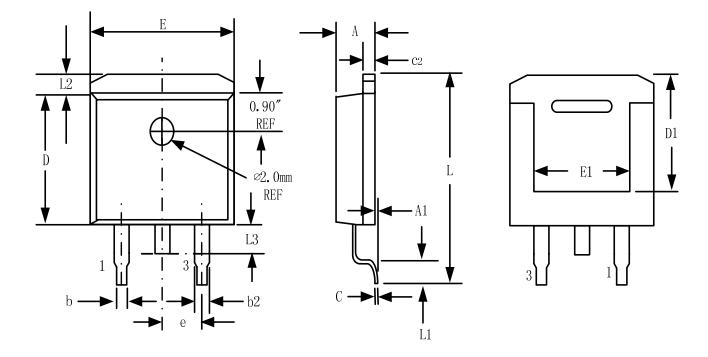
TO-220-3L-C Package Information



Sumbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
с	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.54	0 TYP.	0.100 TYP.		
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.50	0 REF.	0.295 REF.		
Ф	3.400	3.800	0.134	0.150	



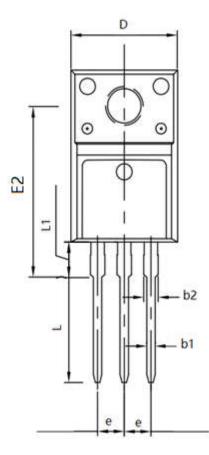
TO-263-3L Package Information

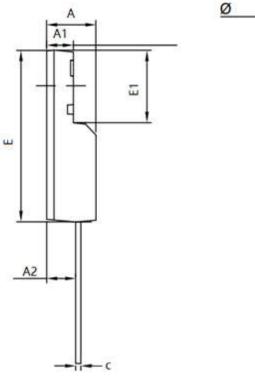


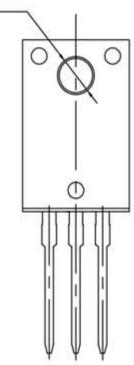
Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.32	4.57	0.170	0.180	
A1	-	0.25		0.010	
b	0.71	0.94	0.028	0.037	
b2	1.15	1.40	0.045	0.055	
с	0.46	0.61	0.018	0.024	
c2	1.22	1.40	0.048	0.055	
D	8.89	9.40	0.350	0.370	
D1	8.01	8.23	0.315	0.324	
E	10.04	10.28	0.395	0.405	
E1	7.88	8.08	0.310	0.318	
е	2.5	4 BSC	0.100	BSC	
L	14.73	15.75	0.580	0.620	
L1	2.29	2.79	0.090	0.110	
L2	1.15	1.39	0.045	0.055	
L3	1.27	1.77	0.050	0.070	



TO-220F Package Information







Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	4.500	4.900	0.177	0.193	
A1	2.340	2.740	0.092	0.108	
A2	2.560	2.960	0.101	0.117	
b1	0.700	0.900	0.028	0.035	
b2	1.180	1.580	0.046	0.062	
С	0.400	0.600	0.016	0.024	
D	9.960	10.360	0.392	0.408	
E	15.670	15.970	0.617	0.629	
E1	6.500	6.900	0.256	0.272	
E2	15.500	16.100	0.610	0.634	
е	2.540 TYP		0.100) TYP	
Φ	3.080	3.280	0.121	0.129	
L	12.640	13.240	0.498	0.521	
L1	3.030	3.430	0.119	0.135	



ATTENTION:

- Any and all NCE products described or contained herein do not have specifications that can handle applications that require extremely high levels of reliability, such as life-support systems, aircraft's control systems, or other applications whose failure can be reasonably expected to result in serious physical and/or material damage. Consult with your NCE representative nearest you before using any NCE products described or contained herein in such applications.
- NCE assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all NCE products described or contained herein.
- Specifications of any and all NCE products described or contained herein stipulate the performance, characteristics, and functions of the described products in the independent state, and are not guarantees of the performance, characteristics, and functions of the described products as mounted in the customer's products or equipment. To verify symptoms and states that cannot be evaluated in an independent device, the customer should always evaluate and test devices mounted in the customer's products or equipment.
- NCE Power Semiconductor CO.,LTD. strives to supply high-quality high-reliability products. However, any and all semiconductor products fail with some probability. It is possible that these probabilistic failures could give rise to accidents or events that could endanger human lives, that could give rise to smoke or fire, or that could cause damage to other property. When designing equipment, adopt safety measures so that these kinds of accidents or events cannot occur. Such measures include but are not limited to protective circuits and error prevention circuits for safe design, redundant design, and structural design.
- In the event that any or all NCE products(including technical data, services) described or contained herein are controlled under any of applicable local export control laws and regulations, such products must not be exported without obtaining the export license from the authorities concerned in accordance with the above law.
- No part of this publication may be reproduced or transmitted in any form or by any means, electronic or mechanical, including photocopying and recording, or any information storage or retrieval system, or otherwise, without the prior written permission of NCE Power Semiconductor CO.,LTD.
- Information (including circuit diagrams and circuit parameters) herein is for example only; it is not guaranteed for volume production. NCE believes information herein is accurate and reliable, but no guarantees are made or implied regarding its use or any infringements of intellectual property rights or other rights of third parties.
- Any and all information described or contained herein are subject to change without notice due to product/technology improvement, etc. When designing equipment, refer to the "Delivery Specification" for the NCE product that you intend to use.
- This catalog provides information as of Mar. 2010. Specifications and information herein are subject to change without notice.